

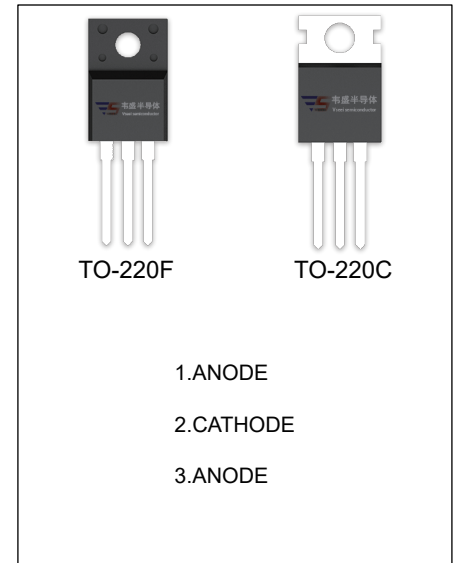
# **SBD1045LCT、SBDF1045LCT** SCHOTTKY BARRIER RECTIFIER

## **MAIN CHARACTERISTICS**

|              |   |
|--------------|---|
| $I_O$        | <b>10 (2×5) A</b>                             |
| $V_{RRM}$    | <b>45 V</b>                                   |
| $T_j$        | <b>150 °C</b>                                 |
| $V_{F(typ)}$ | <b>0.40V (@<math>T_j=125^{\circ}C</math>)</b> |

## **FEATURES**

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



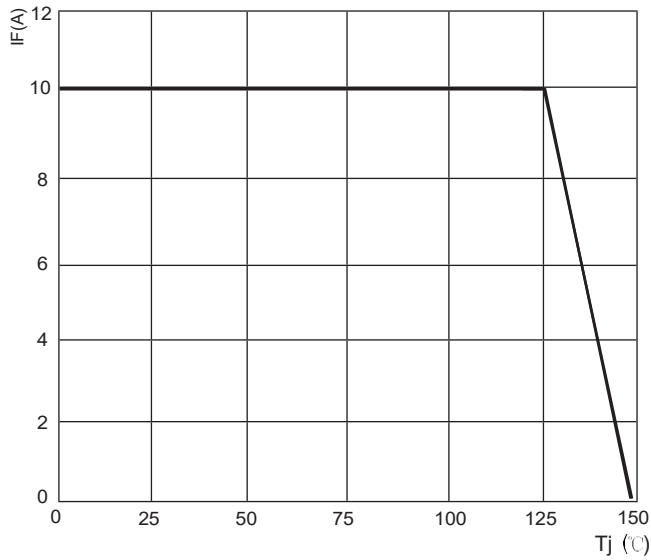
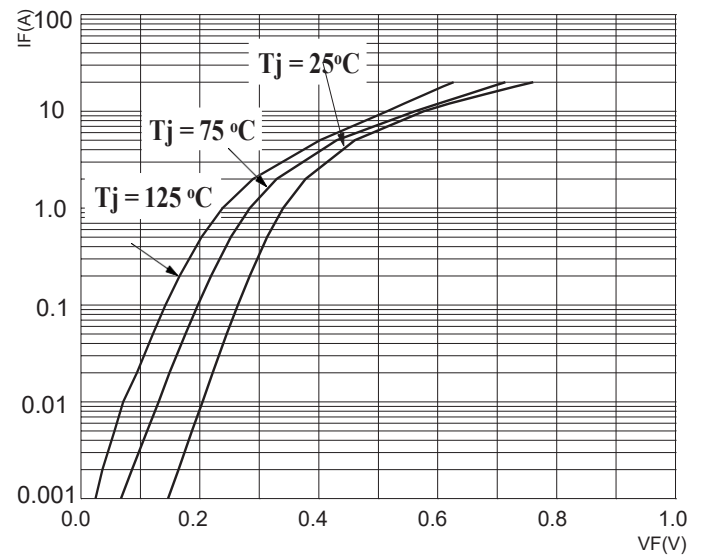
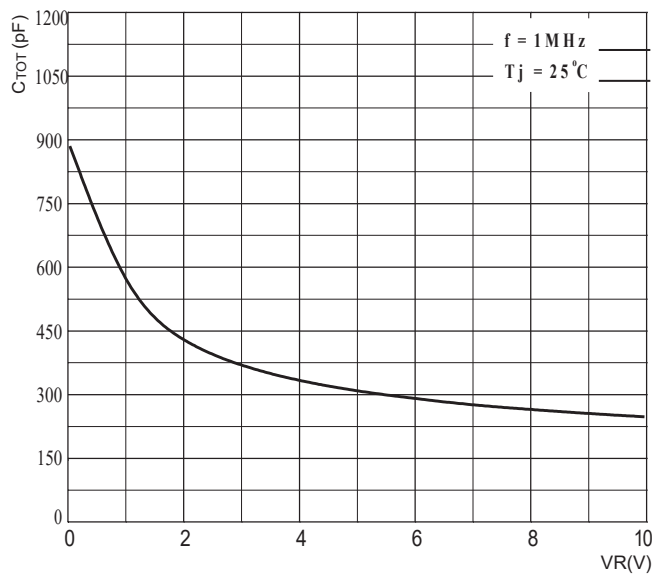
## **MAXIMUM RATINGS ( $T_a=25^{\circ}C$ unless otherwise noted )**

| Symbol          | Parameter  | SBD      |          | Unit          |
|-----------------|--|----------|----------|---------------|
|                 |  | 1045LCT  | F1045LCT |               |
| $V_{RRM}$       | Peak repetitive reverse voltage                                  | 45       |          | V             |
| $V_{RWM}$       | Working peak reverse voltage                                     |          |          |               |
| $V_R$           | DC blocking voltage  |          |          |               |
| $V_{R(RMS)}$    | RMS reverse voltage  | 31.5     |          | V             |
| $I_O$           | Average rectified output current                                 | 10       |          | A             |
| $I_{FSM}$       | Non-Repetitive peak forward surge current (8.3ms half sine wave) | 120      |          | A             |
| $R_{\theta Jc}$ | Thermal resistance from junction to case , $T_c=25^{\circ}C$     | 2.0      | 3.0      | $^{\circ}C/W$ |
| $R_{\theta JA}$ | Thermal resistance from junction to ambient                      | 62.5     |          | $^{\circ}C/W$ |
| $T_j$           | Junction temperature   | 150      |          | $^{\circ}C$   |
| $T_{stg}$       | Storage temperature  | -55~+150 |          | $^{\circ}C$   |

## **ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}C$ unless otherwise specified)**

| Parameter       | Symbol     | Test conditions | Min                | Typ  | Max  | Unit    |
|-----------------|------------|-----------------|--------------------|------|------|---------|
| Reverse voltage | $V_{(BR)}$ | $I_R=1mA$       | 45                 |      |      | V       |
| Reverse current | $I_R$      | $V_R=45V$       | $T_j=25^{\circ}C$  | 50   | 100  | $\mu A$ |
|                 |            |                 | $T_j=125^{\circ}C$ | 20   |      | mA      |
| Forward voltage | $V_F$      | $I_F=3A$        | $T_j=25^{\circ}C$  | 0.42 |      | V       |
|                 |            |                 | $T_j=125^{\circ}C$ | 0.34 |      | V       |
|                 |            | $I_F=5A$        | $T_j=25^{\circ}C$  | 0.46 | 0.55 | V       |
|                 |            |                 | $T_j=125^{\circ}C$ | 0.40 |      | V       |

\*Pulse test: pulse width  $\leq 300\mu s$ , duty cycles  $\leq 2.0\%$ .

**FIG.1: FORWARD CURRENT DERATING CURVE**

**FIG.2: TYPICAL FORWARD CHARACTERISTICS**

**FIG.3: TOTAL CAPACITANCE DERATING CURVE**

**FIG.4: TYPICAL REVERSE CHARACTERISTICS**
